





TEST REPORT IEC 60269-4

Low-voltage fuses

Part 4: Supplementary requirements for fuse-links for the protection of semiconductor devices

Date of issue 2024-12-10

Total number of pages...... 28

Name of Testing Laboratory Suzhou Electrical Apparatus Science Research Institute Co.

preparing the Report...... Ltd.(EETI)

Address Sulv Industry Zone, Liushi Town, Yueqing City, Zhejiang Province,

P.R.China.

Test specification:

Standard.....: IEC 60269-4:2009, IEC 60269-4:2009/AMD1:2012,

IEC 60269-4:2009/AMD2:2016

see also IEC 60269-1:2006, IEC 60269-1:2006/AMD1:2009. IEC

60269-1:2006/AMD2:2014

Test procedure CB Scheme

Non-standard test method: N/A

TRF template used IECEE OD-2020-F1:2022, Ed.1.5

Test Report Form No. IEC60269_4D

Test Report Form(s) Originator: CQC

Master TRF.....: Dated 2023-08-17

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Report No.: 03601-A-24CB0182-S

Test item description	Fuse for protection of semiconductor devices		
Trade Mark	Tengen		
Manufacturer	Zhejiang Tengen Electric Co., Ltd.		
	Sulv Industry Zone, Liushi Town, Yueqing City, Zhejiang Province, P.R.China.		
Model/Type reference	1		
	TGRS3Z-200CQ		
Ratings	Un:DC250V/DC500V/DC750V/AC500V/AC690V/AC800V;		
	In:10A,16A,20A,25A,32A,40A,50A,63A,80A,100A,125A,160A,180A,200A; I1:50kA(DC250V/DC500V/DC750V);100kA(AC500V/AC690V/AC800V);aR.		
TT:50KA(D		DC250V/DC500V/DC750V);100kA(/	(C500V/AC690V/AC800V);aR.
Responsible Testing Laboratory (as applicable), testing procedure and testing location(s):			
☐ CB Testing Laboratory:		Suzhou Electrical Apparatus Science	e Research Institute Co., Ltd.(EETI)
Testing location/ address		No.7 Yonghe Street, Binhe Road,	New District, Suzhou, China
Tested by (name, function, signature).		Fang Gang(Team leader)	ग्रेही
Approved by (name, function, signature)		Chen Yuan (Supervisor)	d1 2/4 >
☐ Testing procedure: CTF Stage 1:			V
Testing location/ address			
Tested by (name, function, signature).			7
Approved by (name, function, signature)		,	*:
Testing procedure: CTF Stage 2:			
Testing location/ address			
Tested by (name + signature)			
Witnessed by (name, function,			4 4
Approved by (name, function,			
signature)			
Testing procedure: CTF Stage 3:			
Testing procedure: CTF Stage 4:			
Testing location/ address			
Tested by (name, function, signature).			
Witnessed by (name, function, signature)			
Approved by (name, function, signature)			
Supervised by (name, function signature)			